

MJE5740, MJE5742

NPN Silicon Power Darlington Transistors

The MJE5740 and MJE5742 Darlington transistors are designed for high-voltage power switching in inductive circuits.

Features

- These Devices are Pb-Free and are RoHS Compliant*

Applications

- Small Engine Ignition
- Switching Regulators
- Inverters
- Solenoid and Relay Drivers
- Motor Controls

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage MJE5740 MJE5742	$V_{CEO(sus)}$	300 400	Vdc
Collector-Emitter Voltage MJE5740 MJE5742	V_{CEV}	600 800	Vdc
Emitter-Base Voltage	V_{EB}	8	Vdc
Collector Current – Continuous – Peak (Note 1)	I_C I_{CM}	8 16	Adc
Base Current – Continuous – Peak (Note 1)	I_B I_{BM}	2.5 5	Adc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2 0.016	W W/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	100 0.8	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.25	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 5 Seconds	T_L	275	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle $\leq 10\%$.

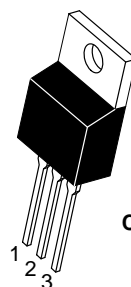
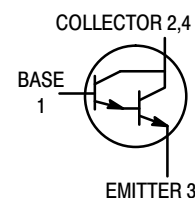
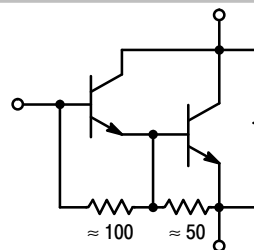
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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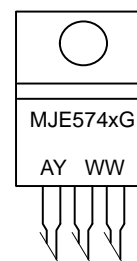
www.onsemi.com

POWER DARLINGTON TRANSISTORS 8 AMPERES 300-400 VOLTS 80 WATTS



TO-220AB
CASE 221A-09
STYLE 1

MARKING DIAGRAM



MJE574x = Device Code
x = 0 or 2
G = Pb-Free Package
A = Assembly Location
Y = Year
WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MJE5740, MJE5742

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS (Note 2)

Collector–Emitter Sustaining Voltage ($I_C = 50\text{ mA}$, $I_B = 0$)	MJE5740 MJE5742	$V_{CEO(sus)}$	300 400	– –	Vdc
Collector Cutoff Current ($V_{CEV} = \text{Rated Value}$, $V_{BE(off)} = 1.5\text{ Vdc}$) ($V_{CEV} = \text{Rated Value}$, $V_{BE(off)} = 1.5\text{ Vdc}$, $T_C = 100^\circ\text{C}$)		I_{CEV}	– –	– 5	mAdc
Emitter Cutoff Current ($V_{EB} = 8\text{ Vdc}$, $I_C = 0$)		I_{EBO}	–	–	75 mAdc

SECOND BREAKDOWN

Second Breakdown Collector Current with Base Forward Biased	$I_{S/b}$	See Figure 6
Clamped Inductive SOA with Base Reverse Biased	RBSOA	See Figure 7

ON CHARACTERISTICS (Note 2)

DC Current Gain ($I_C = 0.5\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$) ($I_C = 4\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$)	h_{FE}	50 200	100 400	– –	–
Collector–Emitter Saturation Voltage ($I_C = 4\text{ Adc}$, $I_B = 0.2\text{ Adc}$) ($I_C = 8\text{ Adc}$, $I_B = 0.4\text{ Adc}$) ($I_C = 4\text{ Adc}$, $I_B = 0.2\text{ Adc}$, $T_C = 100^\circ\text{C}$)	$V_{CE(sat)}$	– – –	– – –	2 3 2.2	Vdc
Base–Emitter Saturation Voltage ($I_C = 4\text{ Adc}$, $I_B = 0.2\text{ Adc}$) ($I_C = 8\text{ Adc}$, $I_B = 0.4\text{ Adc}$) ($I_C = 4\text{ Adc}$, $I_B = 0.2\text{ Adc}$, $T_C = 100^\circ\text{C}$)	$V_{BE(sat)}$	– – –	– – –	2.5 3.5 2.4	Vdc
Diode Forward Voltage (Note 3) ($I_F = 5\text{ Adc}$)	V_f	–	–	2.5	Vdc

SWITCHING CHARACTERISTICS

Typical Resistive Load (Table 1)

Delay Time	$(V_{CC} = 250\text{ Vdc}$, $I_{C(pk)} = 6\text{ A}$ $I_{B1} = I_{B2} = 0.25\text{ A}$, $t_p = 25\text{ }\mu\text{s}$, Duty Cycle $\leq 1\%$)	t_d	–	0.04	–	μs
Rise Time		t_r	–	0.5	–	μs
Storage Time		t_s	–	8	–	μs
Fall Time		t_f	–	2	–	μs

Inductive Load, Clamped (Table 1)

Voltage Storage Time	$(I_{C(pk)} = 6\text{ A}$, $V_{CE(pk)} = 250\text{ Vdc}$ $I_{B1} = 0.06\text{ A}$, $V_{BE(off)} = 5\text{ Vdc}$)	t_{sv}	–	4	–	μs
Crossover Time		t_c	–	2	–	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: Pulse Width 300 μs , Duty Cycle = 2%.

3. The internal Collector–to–Emitter diode can eliminate the need for an external diode to clamp inductive loads. Tests have shown that the Forward Recovery Voltage (V_f) of this diode is comparable to that of typical fast recovery rectifiers.

ORDERING INFORMATION

Device	Package	Shipping
MJE5740G	TO–220 (Pb–Free)	50 Units / Rail
MJE5742G	TO–220 (Pb–Free)	

TYPICAL CHARACTERISTICS

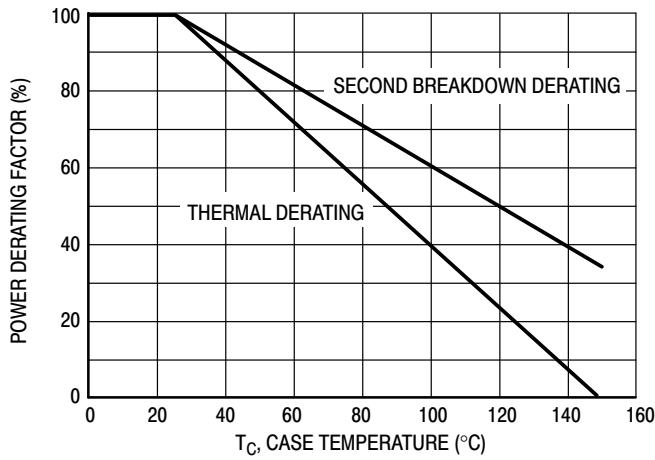


Figure 1. Power Derating

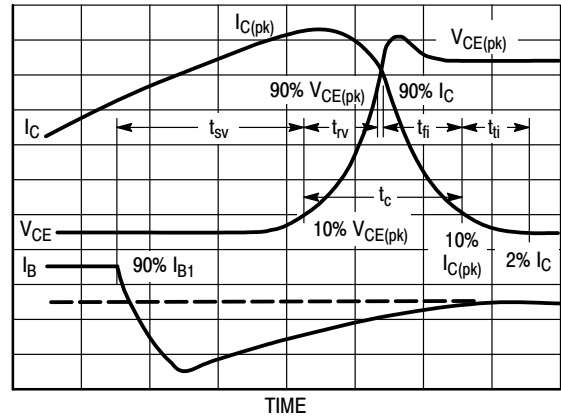


Figure 2. Inductive Switching Measurements

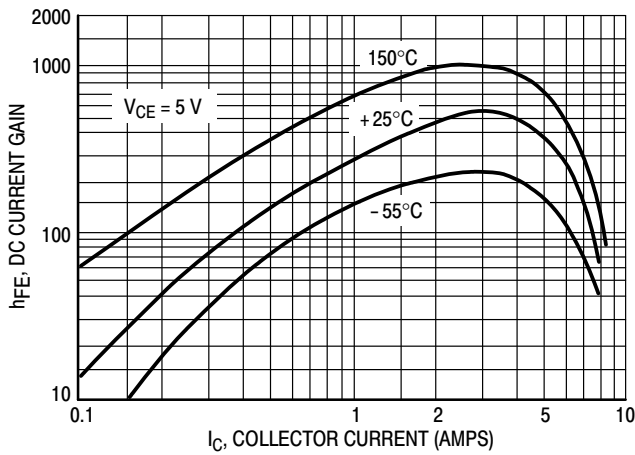


Figure 3. DC Current Gain

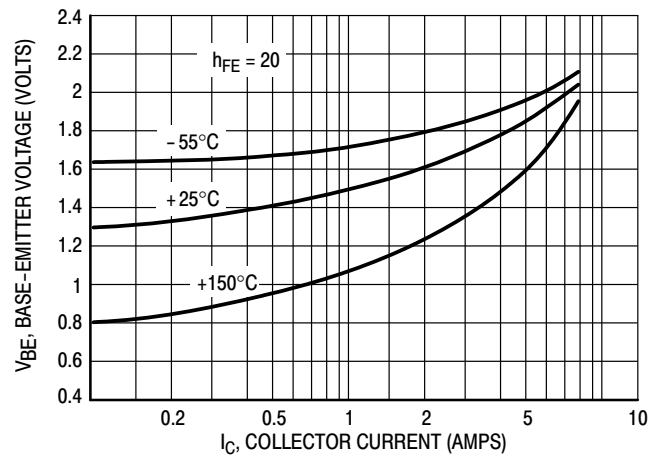


Figure 4. Base-Emitter Voltage

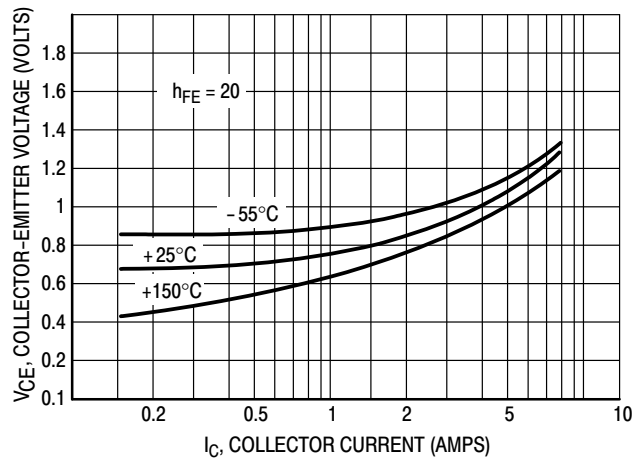


Figure 5. Collector-Emitter Saturation Voltage

MJE5740, MJE5742

Table 1. Test Conditions for Dynamic Performance

REVERSE BIAS SAFE OPERATING AREA AND INDUCTIVE SWITCHING		RESISTIVE SWITCHING
TEST CIRCUITS	<p>DUTY CYCLE ≤ 10% $t_r, t_f \leq 10 \text{ ns}$</p> <p>NOTE: PW and V_{CC} Adjusted for Desired I_C R_B Adjusted for Desired I_{B1}</p>	<p>TUT D 1 -4 V SCOPE</p>
CIRCUIT VALUES	<p>COIL DATA: FERROXCUBE CORE #6656 FULL BOBBIN (~16 TURNS) #16</p> <p>GAP FOR 200 μH/20 A L_{coil} = 200 μH</p> <p>V_{CC} = 30 V V_{CE(pk)} = 250 Vdc I_{C(pk)} = 6 A</p>	<p>V_{CC} = 250 V D1 = 1N5820 OR EQUIV.</p>
TEST WAVEFORMS	<p>OUTPUT WAVEFORMS</p> <p>t_1 ADJUSTED TO OBTAIN I_C</p> $t_1 \approx \frac{L_{\text{coil}} (I_{Cpk})}{V_{CC}}$ <p>TEST EQUIPMENT SCOPE-TEKTRONICS 475 OR EQUIVALENT</p> $t_2 \approx \frac{L_{\text{coil}} (I_{Cpk})}{V_{\text{clamp}}}$	<p>+10 V 0 -9.2 V 25 μs</p> <p>$t_r, t_f < 10 \text{ ns}$ DUTY CYCLE = 1% R_B AND R_C ADJUSTED FOR DESIRED I_B AND I_C</p>

SAFE OPERATING AREA INFORMATION

FORWARD BIAS

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_C = 25^\circ\text{C}$; $T_{J(pk)}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when $T_C \geq 25^\circ\text{C}$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on Figure 6 may be found at any case temperature by using the appropriate curve on Figure 1.

The Safe Operating Area figures shown in Figures 6 and 7 are specified ratings for these devices under the test conditions shown.

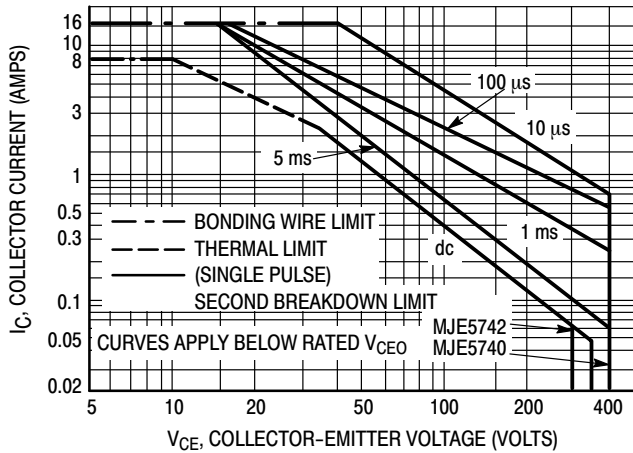


Figure 6. Forward Bias Safe Operating Area

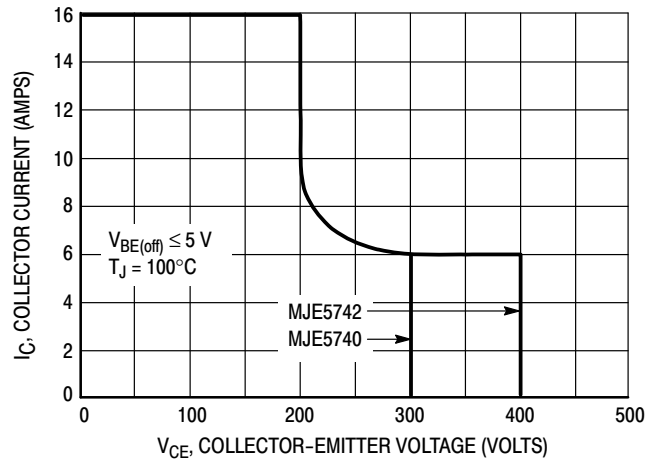


Figure 7. Reverse Bias Safe Operating Area

RESISTIVE SWITCHING PERFORMANCE

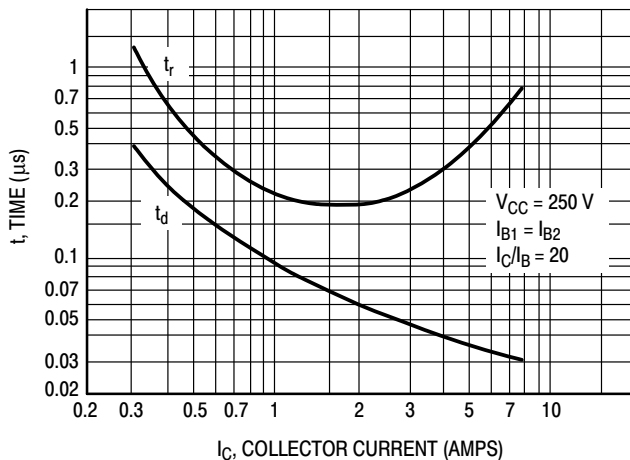


Figure 8. Turn-On Time

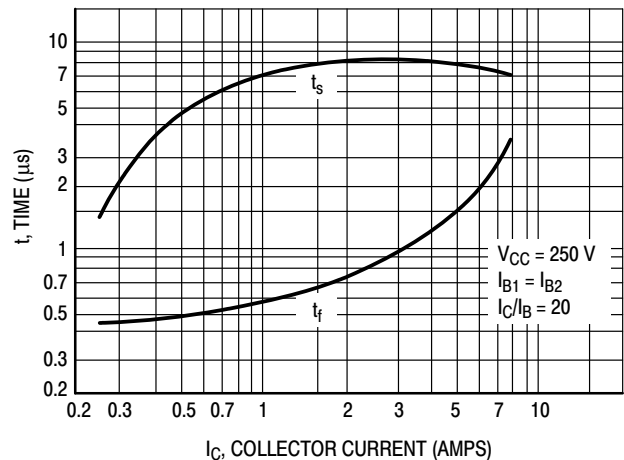


Figure 9. Turn-Off Time

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